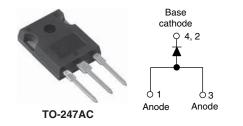


**Vishay Semiconductors** 

### Input Rectifier Diode, 80 A



PRODUCT SUMMARY							
V <sub>F</sub> at 80 A	1.17 V						
I <sub>FSM</sub>	1450 A						
V <sub>RRM</sub>	1600 V						

#### DESCRIPTION/FEATURES

The VS-80EPS16PbF rectifier High Voltage Series has been optimized for very low forward voltage drop, with moderate leakage. The glass passivation technology used has reliable operation up to 150 °C junction temperature.



COMPLIANT

Typical applications are in input rectification and these products are designed to be used with Vishay Semiconductors switches and output rectifiers which are available in identical package outlines.

This product has been designed and qualified for industrial level.

• Compliant to RoHS Directive 2002/95/EC

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I <sub>F(AV)</sub>	Sinusoidal waveform	80	A						
V <sub>RRM</sub>		1600	V						
I <sub>FSM</sub>		1450	A						
V <sub>F</sub>	80 A, T <sub>J</sub> = 25 °C	1.17	V						
TJ		- 40 to 150	°C						

<b>VOLTAGE RATINGS</b>			
PART NUMBER	V <sub>RRM</sub> , MAXIMUM PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> AT 150 °C mA
VS-80EPS16PbF	1600	1700	1

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Maximum average forward current	I <sub>F(AV)</sub>	$T_C = 100 \ ^{\circ}C$ , 180° conduction half sine wave	80						
Maximum peak one cycle	I <sub>FSM</sub>	10 ms sine pulse, rated V <sub>RRM</sub> applied	1450	А					
non-repetitive surge current		10 ms sine pulse, no voltage reapplied	1500						
Maximum 12t fax fusing	l <sup>2</sup> t	10 ms sine pulse, rated V <sub>RRM</sub> applied	10 500	A <sup>2</sup> s					
Maximum I <sup>2</sup> t for fusing	1-1	10 ms sine pulse, no voltage reapplied 11 250		A-S					
Maximum I <sup>2</sup> √t for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	105 000	A²√s					

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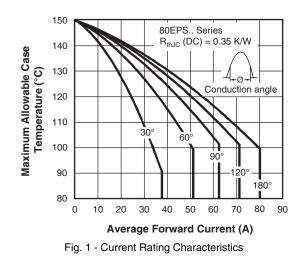
**Vishay Semiconductors** 

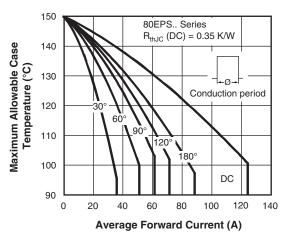
Input Rectifier Diode, 80 A

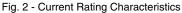


ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CON	IDITIONS	VALUES	UNITS				
Maximum forward voltage drop	V <sub>FM</sub>	80 A, T <sub>J</sub> = 25 °C		1.17	V				
Forward slope resistance	rt	T.I = 150 °C		3.17	mΩ				
Threshold voltage	V <sub>F(TO)</sub>	1) = 150 C		0.73	V				
Maximum reverse leakage current		$T_J = 25 ^{\circ}C$		0.1	mA				
Maximum reverse leakage current	IRM	T <sub>J</sub> = 150 °C	$V_R$ = Rated $V_{RRM}$	1.0	IIIA				

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		- 40 to 150	°C			
Maximum thermal resistance, junction to case		R <sub>thJC</sub>	DC operation	0.35				
Maximum thermal resistance, junction to ambient		R <sub>thJA</sub>		40	°C/W			
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.2				
Approvimeto weight				6	g			
Approximate weight				0.21	oz.			
Mounting torque	minimum			6 (5)	kgf ⋅ cm			
Mounting torque	maximum			12 (10)	(lbf ⋅ in)			
Marking device			Case style TO-247AC (JEDEC)	80EPS16				







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Input Rectifier Diode, 80 A

**Vishay Semiconductors** 

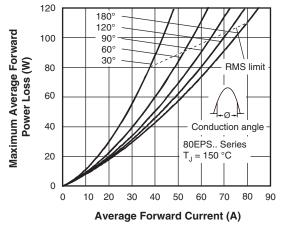
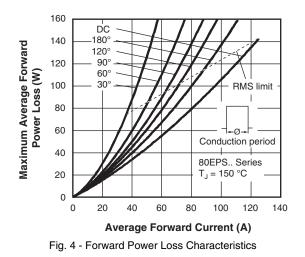
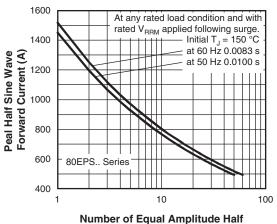


Fig. 3 - Forward Power Loss Characteristics





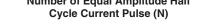


Fig. 5 - Maximum Non-Repetitive Surge Current

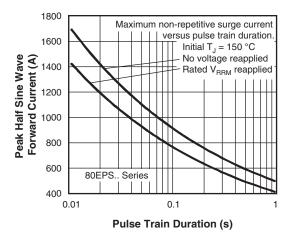


Fig. 6 - Maximum Non-Repetitive Surge Current

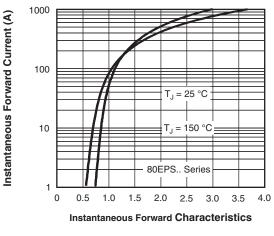


Fig. 7 - Forward Voltage Drop Characteristics

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Vishay Semiconductors

Input Rectifier Diode, 80 A



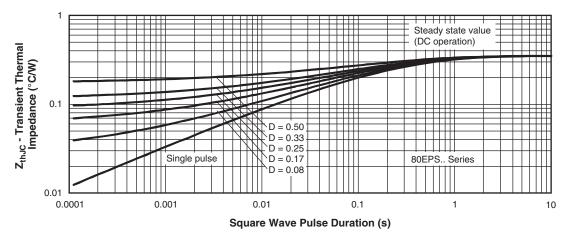


Fig. 8 - Thermal Impedance Z<sub>thJC</sub> Characteristics

### **ORDERING INFORMATION TABLE**

Device code	VS-	80	E	Р	S	16	PbF
	1	2	3	4	5	6	7
	<ol> <li>Vishay Semiconductors product</li> <li>Current rating (80 = 80 A)</li> <li>Circuit configuration:</li> </ol>						
	4	- Pac P =	Single o kage: TO-247	AC			
	6	S = - Volt	e of silic Standar tage rati one = St	rd recove ng (16 =	1600 V	')	
		• Pl	bF = Lea	ad (Pb)-f	free		

LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?95223						
Part marking information	www.vishay.com/doc?95226						

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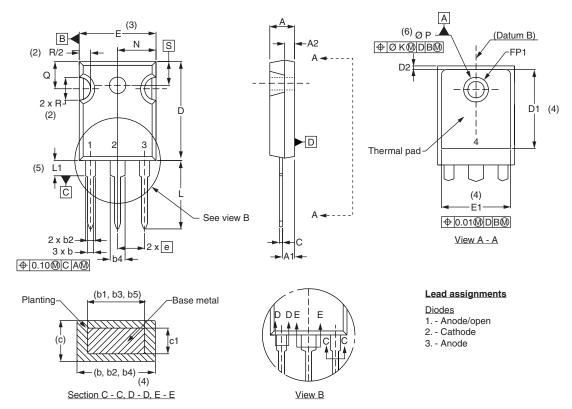
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### **Outline Dimensions**





#### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIMETERS		INC	HES	NOTES		SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STNIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STWBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209			D2	0.51	1.30	0.020	0.051	
A1	2.21	2.59	0.087	0.102			E	15.29	15.87	0.602	0.625	3
A2	1.50	2.49	0.059	0.098			E1	13.72	-	0.540	-	
b	0.99	1.40	0.039	0.055			e	5.46	BSC	0.215	BSC	
b1	0.99	1.35	0.039	0.053			FK	2.	54	0.0	)10	
b2	1.65	2.39	0.065	0.094			L	14.20	16.10	0.559	0.634	
b3	1.65	2.37	0.065	0.094			L1	3.71	4.29	0.146	0.169	
b4	2.59	3.43	0.102	0.135			Ν	7.62	BSC	0	.3	
b5	2.59	3.38	0.102	0.133			ΦP	3.56	3.66	0.14	0.144	
с	0.38	0.86	0.015	0.034			Φ <b>P1</b>	-	6.98	-	0.275	
c1	0.38	0.76	0.015	0.030			Q	5.31	5.69	0.209	0.224	
D	19.71	20.70	0.776	0.815	3		R	4.52	5.49	1.78	0.216	
D1	13.08	_	0.515	-	4		S	5.51	BSC	0.217	BSC	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

<sup>(4)</sup> Thermal pad contour optional with dimensions D1 and E1

<sup>(5)</sup> Lead finish uncontrolled in L1

(6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

<sup>(7)</sup> Outline conforms to JEDEC outline TO-247 with exception of dimension c

Document Number: 95223



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